



TET ESTEL AS
ESTONIA

**December
2015**

**Series
D443-800**

**Rectifier Press-Pack
Diode
Type D443-800**

Designed for rectifiers and industrial applications

Maximum mean forward current				I _{FAV}	800 A	
Maximum repetitive peak reverse voltage				U _{RRM}	3400 ÷ 4400 V	
Reverse recovery time				trr (typ)	40 µs	
U _{RRM} , V	3400	3600	3800	4000	4200	4400
Voltage code	34	36	38	40	42	44
Tvj, °C	- 60 ÷ 150					

MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	D443-800	Conditions	
I _{FAV}	Mean forward current	A	800 1430	Tc=110 °C, Tc=55 °C, 180° half-sine wave, 50 Hz	
I _{FRMS}	RMS forward current	A	1250	Tc=110 °C	
I _{FSM}	Surge forward current	kA	13,0 14,0	Tvj=150°C Tvj=25°C	tp=10 ms UR=0
I ² t	Limiting load integral	kA ² s	845 980	Tvj=150°C Tvj=25°C	
U _{RRM}	Repetitive peak reverse voltage	V	3400÷4400	Tj min≤Tvj≤Tjm 180° half-sine wave, 50 Hz	
U _{RSR}	Non-repetitive peak reverse voltage	V	3500÷4500	Tj min≤Tvj≤Tjm 180° half-sine wave tp=10 ms, Single pulse	
T _{stg}	Storage temperature	°C	-60÷80		
Tvj	Junction temperature	°C	-60÷150		

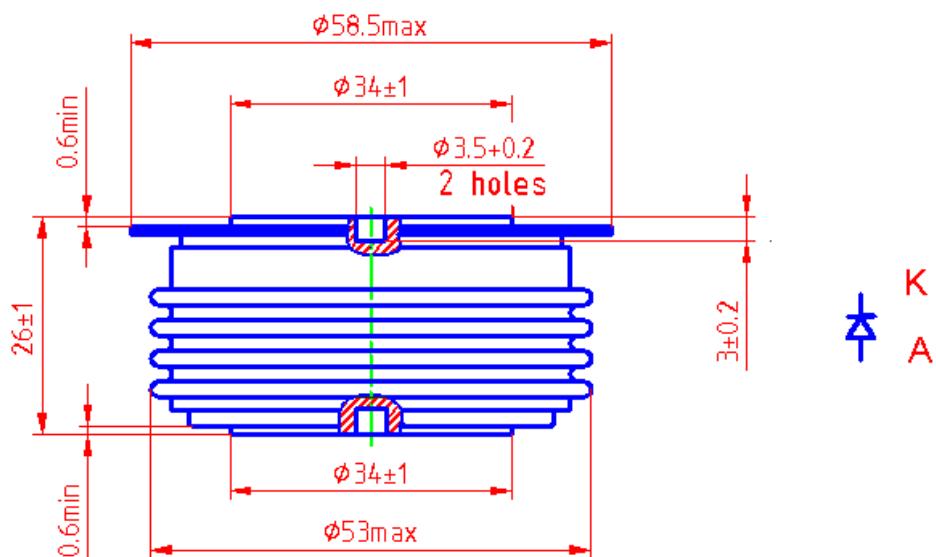
CHARACTERISTICS

U _{FM}	Peak forward voltage	V	1,8	Tvj=25°C, I _{TM} =3,14 I _{AV}
U _{F(TO)}	Threshold voltage	V	0,8	Tvj=150°C 1,57 I _{AV} < I _T <4,71 I _{AV}
R _T	Forward slope resistance	mΩ	0,4	
I _{RRM}	Repetitive peak reverse current	mA	50	Tvj=150°C, UR= U _{RRM}

CHARACTERISTICS				
Symbols and parameters		Units	D443-800	Conditions
Qrr	Recovered charge (typ)	µC	2500	Tvj=150°C If=800 A diR/dt =10 A/µs UR=100V
trr	Reverse recovery time (typ)	µs	40	
Irrm	Peak reverse recovery current (typ)	A	125	
Rthjc	Thermal resistance junction to case	°C/W	0,03	
				Direct current, double side cooled

ORDERING				
	D	443	800	40
	1	2	3	4

1. Diode
2. Design version
3. Mean forward current, A
4. Voltage code (40=4000 V)



Mounting force : 13 ÷ 19 kN
Weight : 320 grams